

# isc Silicon PNP Power Transistor

#### **DESCRIPTION**

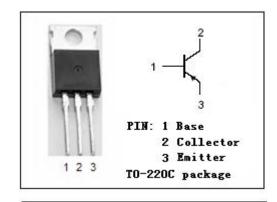
- · Collector-Emitter Breakdown Voltage-
  - :  $V_{(BR)CEO}$ = -80V(Min)
- · Collector Power Dissipation-
  - :  $P_C$ = 40W@  $T_C$ = 25°C
- · Low Collector Saturation Voltage-
  - :  $V_{CE(sat)}$ = -0.5V(Max)@ I<sub>C</sub>= -4A
- Complement to Type 2SD1362
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

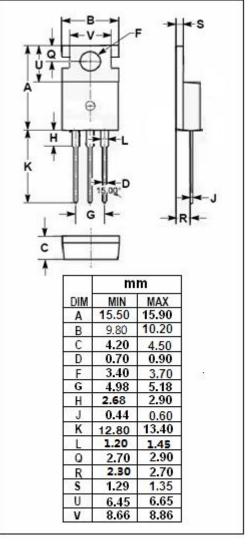
#### **APPLICATIONS**

- · High current switching applications.
- · Power amplifier applications.

## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	-100	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-80	V
V <sub>ЕВО</sub>	Emitter-Base Voltage -5 V		V
Ic	Collector Current-Continuous	-7	Α
I <sub>B</sub>	Base Current-Continuous -1		А
P <sub>C</sub>	Collector Power Dissipation @Ta=25°C	1.5	W
	Collector Power Dissipation @T <sub>C</sub> =25°C	40	v V
TJ	Junction Temperature	150 °C	
T <sub>stg</sub>	Storage Temperature -55~150		$^{\circ}$







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2SB992

### **ELECTRICAL CHARACTERISTICS**

Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -30mA; I <sub>B</sub> = 0	-80			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -4A; I <sub>B</sub> = -0.4A			-0.5	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = -4A; I <sub>B</sub> = -0.4A			-1.4	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = -100V ; I <sub>E</sub> = 0			-5	μА
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-5	μА
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -1A; V <sub>CE</sub> = -1V	70		240	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -4A; V <sub>CE</sub> = -1V	30			

### ♦ h<sub>FE-1</sub> Classifications

0	Y
70-140	120-240

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